

























We grow PROUD for you.all of us.

SWISS LAB-GROWN DIAMOND





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JUNE 2022



























No Comment

GLOBAL CHALLENGE:



SUSTAINABLE DEVELOPMENT AND CLIMATE CHANGE













































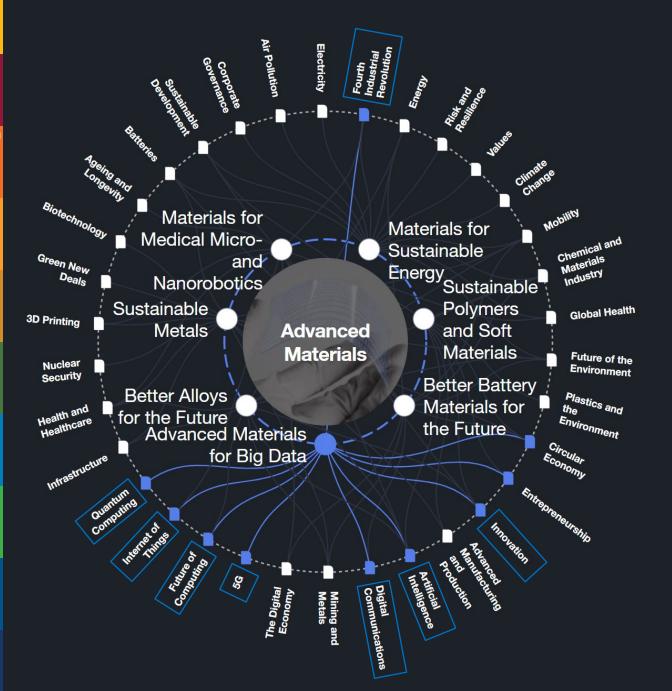














RAPID INNOVATION AND LOWERING COSTS HAVE DRAMATICALLY INCREASED ELECTRONIC PRODUCTS AND DIGITAL TECHNOLOGY, WITH MANY BENEFITS. THIS HAS LED TO INCREASE IN DIGITAL SERVICES, THE USE EQUIPMENT. **ELECTRONIC UNINTENDED CONSEQUENCE** OF THIS IS A **BALLOONING** OF ELECTRONIC AND ELECTRICAL **ENERGY** CONSUMPTION, E-WASTE, NATURAL RESOURCES AND CO₂ EMISSION.

WORLD ECONOMIC FORUM

INDUSTRY & TECHNOLOGY CHALLENGE – PROBLEM ADVANCED MATERIALS





FOR 1 CARAT EXTRACTED*

- 1000+ TONS OF EARTH REMOVED
- 3000+ LITERS OF WATERUSED
- 500+ KG OF AIR POLLUTION RELEASED
- 100+ KG OF CARBON DIOXIDE EMITTED

SUPPLY OF HIGH-GRADE DIAMOND IS A CHALLENGE.

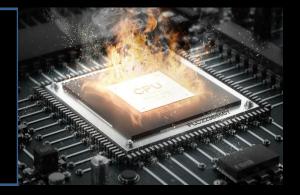
NATURAL DIAMOND EXTRACTION HAS STRONG **NEGATIVE IMPACTS** ON **THE** ENVIRONMENT, HEALTH, WATER USAGE, SOCIAL JUSTICE AND AIR QUALITY.

* Environmental Impacts of Mined Diamonds, Dr. Gbemi Oluleye, 2021



IMPACT OF TEMPERATURE ON SEMICONDUCTORS

- REDUCE DEVICE LIFETIME
- LIMIT THE DEVICE PERFORMANCE
- INCREASE THE POWER CONSUMPTION



CURRENT METHODS FOR THERMAL MANAGEMENT

NO LONGER EFFECTIVE TO ADDRESS NEW GENERATION OF SEMICONDUCTORS

"ICT'S SHARE OF GLOBAL GREENHOUSE GAS EMISSIONS ACTUALLY LIES BETWEEN 2.1-3.9 %. ICT GHG EMISSIONS COULD BE AS HIGH AS 8 % BY 2025»

MP CVD LAB-GROWN DIAMOND

Microwave Plasma Chemical Vapor Depositio





ADVANTAGES OF MP CVD DIAMOND

- THE HIGHEST KNOWN THERMAL CONDUCTIVITY
- THE HIGHEST KNOWN RESISTANCE TO THERMAL SHOCK
- THE BROADEST OPTICAL TRANSMISSION SPECTRUM
- A WIDE ELECTRONIC BAND GAP
- A VERY LOW COEFFICIENT OF FRICTION
- EXCELLENT ELECTRIC INSULATOR PROPERTIES
- EXCELLENT P-TYPE (IIB TYPE) SEMICONDUCTOR PROPERTIES
- CHEMICALLY AND BIOLOGICALLY INERT (RESISTANCE TO ANY ACID AND BASE)

PARAMETER	Si	SiC	GaN	DIAMOND
THERMAL CONDUCTIVITY [W/M.K]	130	460	140	2000
BANDGAP [EV]	1.12	3.26	3.45	5.45
Critical electric field (E _C) [MV/cm]	0.3	2.2	3.7	10
MOBILITY [CM ² /VS]	1450	700	1200	2000
BALIGA FIGURE OF MERIT (RELATIVE TO SI)	1	500	1300	23000

DIAMOND IS FAMOUSLY A VERY HARD MATERIAL, BUT IT ALSO HAS THE HIGHEST CHEMICAL STABILITY, AS WELL AS UNIQUE CONDUCTIVITY AND THERMAL SHOCK RESISTANCE.

CVD DIAMOND OFFERS OUTSTANDING PHYSICAL PROPERTIES	TO A BROAD RANGE OF HIGH-TECH APPLICATIONS
Transparency	OPTICS
BIOCOMPATIBLE	MEDICAL DEVICES
TAILORED ATOMIC DEFECTS	Quantum & Sensors
Hardest Material on Earth	MICROMECHANICS
BEST MATERIAL TO DISSIPATE HEAT	PHOTONICS & ELECTRONICS
EST MATERIAL TO SUSTAIN HIGH VOLTAGE	Power Electronics
TERIAL TO WORK IN HARSH ENVIRONMENT	SPACE & DETECTORS



PROUD TECHNOLOGY: DEMONSTRATED TECHNOLOGY

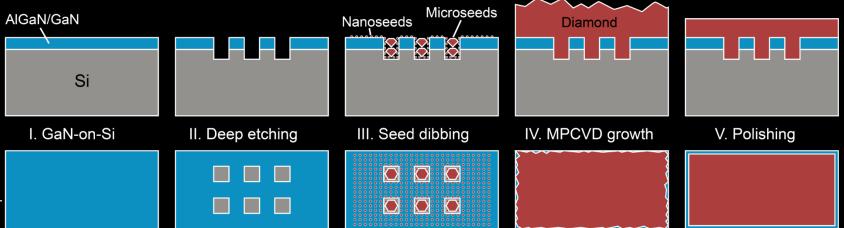
PATENT FILLED WITH TTO

OUR STATE-OF-ART FABRICATION METHOD



INSPIRED BY AN AGRICULTURAL METHOD





SEED DIBBLING DIAMOND GROWTH

- Reliable method to grow high quality diamond on GaN
- COMPLETELY SOLVED THE ISSUE OF DELAMINATION
- ENABLED THE POLISHING OF DIAMOND
- OPENS PATHS FOR THE DEVELOPMENT OF FUTURE DEVICES

DIAMONDTRANSISTORS ON GAN

- EXCELLENT PERFORMANCES WITH A SIMPLE STRUCTURE AND FABRICATION PROCESS
- HIGH POTENTIALS FOR INTEGRATED CIRCUITS WITH GAN (CMOS, LOGICS, GATE DRIVER, POWER SWITCHES)

DIAMOND NEAR JUNCTION HEAT SPREADERS

- HIGHLY EFFICIENT IN REDUCING THE THERMAL RESISTANCES (2.5 X) AND THERMAL GRADIENTS
- THE THERMAL PERFORMANCE OF GAN-ON-SI WAS UPGRADED TO SIMILAR PERFORMANCES OF GAN-ON-DIAMOND SUBSTRATES

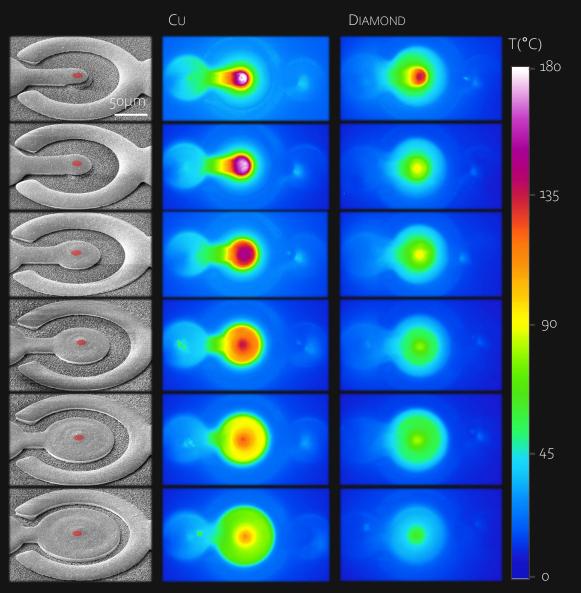




PROUD TECHNOLOGY: DEMONSTRATED TECHNOLOGY



STEADY-STATE TEMPERATURE WITH HEAT SPREADERS



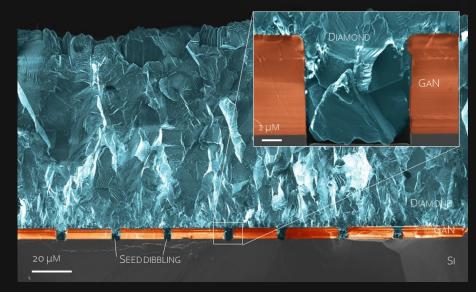


OUR STATE-OF-ART FABRICATION METHOD

DIAMOND HEAT SPREADERS ARE VERY EFFICIENT:

- 3 µM DIAMOND ON AFFORDABLE GAN-ON-SI SUBSTRATES
- 50°C OFTEMPERATURE REDUCTION!
- ELECTRONIC LIFETIME MULTIPLY BY **5**!
- THERMAL DISSIPATION CAPACITY MULTIPLY BY **7** (VS SI OR GAN)!

CVD DIAMOND GROWTH ON GAN-ON-SI



PATENT FILLED WITH TTO



NEXT GENERATION OF SEMI-CONDUCTOR WAFER

TRI WAFER DIAMOND ON GAN ON SI WITH ENHANCED PHYSICAL PROPERTIES THAN TRADITIONAL ELECTRONIC WAFERS AT AN AFFORDABLE PRICE



- HIGH QUALITY SWISS LAB-GROWN DIAMOND
- Cost Effective & Value for Money
- RELIABLE SUPPLY CHAIN
- ETHICAL & SUSTAINABLE





PROUD TECHNOLOGY: ADVANCED MATERIALS

PRODUCTS Π SOLUTIONS Π SERVICES

PROUD TECH

SWISS LAB-GROWN DIAMOND





LUXURY

- AS-GROWN OR PRE-SHAPED
- CUT & POLISHED
- FANCY COLOR
- MICRO-MECHANICS
- CERTIFIED BY GIA, IGI, HRD, GGTL
- 100 % SWISS MADE
- 100 % ETHICAL AND SUSTAINABLE
- 100 % TRACEABLE

HIGH-TECH

■ SEMICONDUCTOR

- TRI-WAFER Diamond on GaN on Si (EPFL IP)
- BI-WAFER Diamond on GaN (EPFL IP)

■ HIGH VOLTAGE

DIAMOND-BASED TRANSISTORS

■ HIGH FREQUENCIES

- DIAMOND-BASED POWER AMPLIFIER
- HIGH ENERGY LASER
- SENSOR
 - AGGRESSIVE ENVIRONMENT (SPACE, RADIATION, CHEMICALS)
 - VERY LOW MAGNETIC FIELD DETECTION (MEDICAL, MATERIAL CHARACTERIZATION)

LAB ACHIEVEMENTS

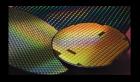
HIGH QUALITY DIAMOND ON SEMICONDUCTOR SUBSTRATE

- HIGH-QUALITY LAB-GROWN DIAMOND ON GAN
- PATENTED TECHNOLOGY



LAB ONGOING PROJECTS

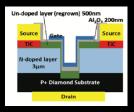
HIGH QUALITY DIAMOND ON ≠ SEMICONDUCTOR SUBSTRATE



DIAMOND-BASED PIN DIODE HETEROSTRUCTURE

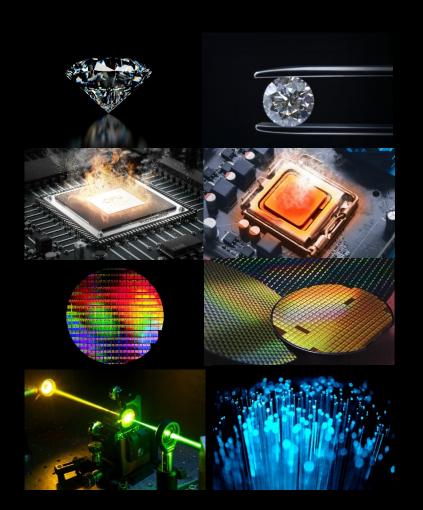


HIGH VOLTAGE P-CHANNEL MOSFET



NOVELTY + SCALABILITY + IMPACT PROUD TECHNOLOGY





NOVEL TECHNOLOGY & APPROACH: ONGOING PATENT FILING WITH THE EPFL TTO. NO PAST RECORDS OF SUCCESSFUL DIRECT DIAMOND GROWTH ON GAN-ON-SI CHIP. COMPLETE NEW APPROACH OF PRODUCING A SEMICONDUCTORS DIAMOND ON GAN BI/TRI-WAFERS



SCALABLE TECHNICAL SOLUTION: MANUFACTURING SYSTEM AND PROCESS CAPABLE TO ADAPT EASILY TO INCREASED WORKLOAD OR MARKET DEMANDS. It'S ABLE TO BENEFIT FROM ECONOMIES OF SCALE AND QUICKLY RAMP UP PRODUCTION.



TARGETED IMPACT: REDUCE ENVIRONMENT IMPACTS. REMOVE TODAY'S HEAT MANAGEMENT LIMITATIONS TO UNLOCK POWER ELECTRONICS POTENTIAL





































PROUD TECHNOLOGY: CVD LAB-GROWN DIAMOND

SWISS LAB-GROWN DIAMOND



100 % REUSABLE DIAMOND SUBSTRATE



CARBON DIOXIDE EMITTED

COMPENSATED



CLOSED LOOP WATER-CIRCUIT



100 % GREEN ENERGY SWISS

CO₂ FROM THE AIR SWISS-

MADE SOLUTION







DIAMOND SUBSTRATE AS A SEED MATERIAL

GASES ARE INTRODUCED IN THE DEPOSITION CHAMBER

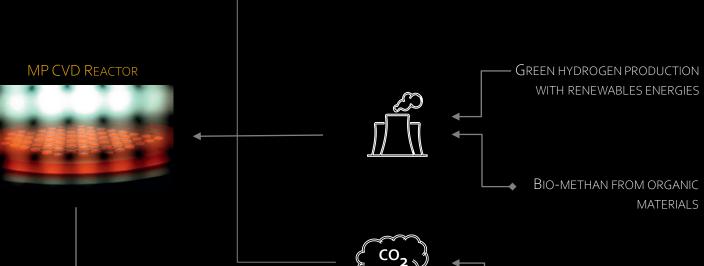
PLASMA IS FORMED

DIAMOND GROWTH STARTS



CUT & POLISH



































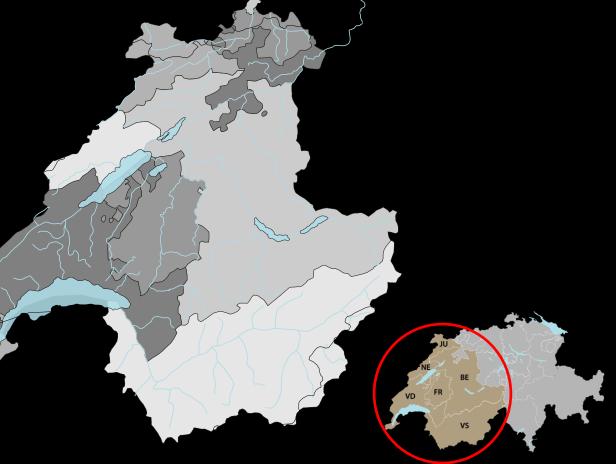




PROUD TECHNOLOGY: CVD LAB-GROWN DIAMOND

SWISS LAB-GROWN DIAMOND





PRODUCTION SITE (SUISSE ROMANDE)

- EQUIPMENT (REACTORS FOR GROWTH & POST-TREATMENTS)
- 20 MIN FROM EPFL AND 40 MIN FROM GENEVA
- ACCESS TO SWISS RENEWABLES ENERGIES
- SECURED AREA

TRANSFORMATION SITE (GENEVA, FREE PORTS)

- **EQUIPMENT (POLISHING MACHINES, LASER SYSTEMS & CHEMICALS)**
- DIRECT ACCESS TO PARTNERS & CUSTOMERS
- EASY ACCESS TO DIAMOND SETTER
- ACCESS TO LAB PARTNERS (GGTL)
- SECURED AREA

STRATEGIC PARTNERS (SWITZERLAND, FRANCE, GERMANY)









Certified



























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SWISS LAB-GROWN DIAMOND





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NIQUE
IAMOND

TECHNOLOGY

JUNE 2022

MARKETS & TRENDS: OVERVIEW



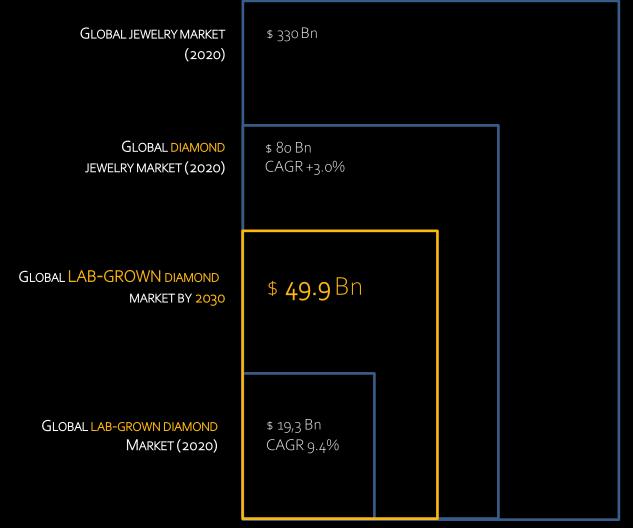








HIGH-TECH







MARKET LANDSCAPE

TARGETED HIGH-TECH COMPANIES









POWER ELECRTONICS

SUMITO ELECTRIC **EATON** INFINEON L₃HARRIS NXO

TOSHIBA FUJI ELECTRIC

MICROSEMI CORPORATION

STMICROELECTRONICS

ROCKWELL AUTOMATION TEXAS INSTRUMENTS

PRYSMIAN GROUP

RENESAS

MITSUBISHI ELECTRIC

QUANTUM COMPUTING

QUANTUM BRILLIANCE **PSI QUANTUM** XANADU Q-CTRL SEEQC DWAVE

HARDWARE

DOVER MICROSYSTEMS **TENSTORRENT** RASPBERRY PI MSI CLOUNIX

SEMICONDUCTOR MANUFACTURER FOUNDRY

WIN SEMICONDUCTORS TSMC SAMSUNG POWERCHIP **HUAHONG GROUP GLOBAL FOUNDRIES** TOWER SEMICONDUCTOR

SEMICONDUCTOR MANUFACTURER WAFER

SILTRONIC **TMGCORE** SOITEC IQE

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FABLESS

AEONSEMI

WILIOT

USOUND

AEPONYX

SCALINX

KIOXIA CANSEMI ZTE **SMART PHOTONICS**

SENSORS

SOREXSENSORS SKYRORA DISPLAY

LIDAR

LEDDAR TECH LUNEWAVE SOSLAB

AI CHIPS CHIP DESIGNER

KNERON SAMSUNG **ENFLAME** INTEL **UNTETHER AI** NVIDIA **ANOTHER BRAIN** HUAWEI AMD HAILO THALES CEREBRAS



MARKET LANDSCAPE

TARGETED PRESTIGIOUS LUXURY BRANDS



Cartier

SWAROVSKI





























BREITLING

JAEGER-LECOULTRE

ROLEX



TAGHeuer

OCITIZEN



 Ω OMEGA

BULOVA



DAVID YURMAN

MOVADO

Cartier







MARCO BICEGO

TUDOR

∜>

GREEN WORLD DIAMONDS

IWC

SCHAFFHAUSEN

HARRY WINSTON





LAGOS

 ∞

PANDÖRA^{*}













PATEK PHILIPPE

H

HUBLOT

AUDEMARS PIGUET



































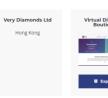














COMPETITIVE ANALYSIS





DIAMOND-ON-GAN

■ FUJITSU LABORATORIES: FUJITSU AIMS TO COMMERCIALIZE IMPROVED-HEAT-DISSIPATION GAN HEMT AMPLIFIERS IN YEAR 2022 FOR USE IN WEATHER RADAR SYSTEMS AND NEXT-GENERATION WIRELESS COMMUNICATION SYSTEMS. THEY USE A DIFFERENT APPROACH THAN PROUD TECHNOLOGY, USING A MIX OF DIAMOND AND GRAPHITE.

GaN-on-Diamond

- ELEMENT SIX (R&D)
- AKASH SYSTEMS (SPACE APPLICATIONS: POWER AMPLIFIER AND RADIO-TRANSMITTER BASED ON GAN-ON-DIAMOND SUBSTRATE). AKASH SYSTEMS AIMS TO DEVELOP A NEW GENERATION OF SMALLER, LIGHTER, MORE EFFICIENT SATELLITES AND THE COMPONENTS THAT POWER THEM TO PAVE THE WAY FOR LOWER LAUNCH COSTS, LOWER COST PER BIT, MORE LAUNCH CYCLES, IMPROVED ACCESS, AND HIGHER COMMUNICATION SPEEDS.
- QORVO (MILITARY AND TELECOM 5G, 6G 7G APPLICATIONS): QORVO IS AN AMERICAN SEMICONDUCTOR COMPANY THAT DESIGNS, MANUFACTURES, AND SUPPLIES RADIO-FREQUENCY SYSTEMS FOR APPLICATIONS THAT DRIVE WIRELESS AND BROADBAND COMMUNICATIONS, AS WELL AS FOUNDRY SERVICES. THEY WORK WITH GAN-ON-DIAMOND TECHNOLOGY FOR MILITARY APPLICATIONS (WITH LOCKHEED MARTIN, DARPA PROJECT).
- RFHIC CORPORATION: RFHIC IS A COMPANY SPECIALIZED IN GAN TECHNOLOGY FOR THE FABRICATION OF MW GENERATOR SYSTEM. RFHIC CORPORATION PURCHASED GAN ON DIAMOND IP FROM E6 A PART OF THE DEBEER'S GROUP BACK IN 2017 AND HAS DEVELOPED THE WORLD'S FIRST COMMERCIALIZED GAN ON DIAMOND TRANSISTOR FOR DEFENSE, MILCOM, RF ENERGY, AND COMMUNICATION APPLICATIONS. THEY DO NOT PUBLICLY COMMERCIALIZE ANY GAN ON DIAMOND TRANSISTOR SO FAR. THEY ONLY OFFER GAN-ON-SIC TRANSISTOR.
- MITSUBISHI FLECTRIC CORP
- DIAMOND FOUNDRY

GRAPHENE

CARDEA
PARAGRAF
NANOTECH ENERGY
SKELETON TECHNOLOGIES

GALLIUM NITRIDE GAN

GAN SYSTEMS
VISIC TECHNOLOGIES
EXAGAN

SILICON CARDIDE SIC

SGKS GENESIC PALLIDUS



COMPETITIVE ANALYSIS



Europe and Middle East: ~0.5 Mcts

- AOTC
- Ziemer Technologies
- Green Rocks
- Lusix

PROUD

US: ~1 Mcts

- Diamond Foundry
- Lightbox/Element Six
- Washington Diamonds

We Are Here ©

India: ~1.5 Mcts

- Creative Technologies
- New Diamond Era
- Diamond Elements
- ALTR

Russia: ~0.2 Mcts

- Wonder Technologies
- New Diamond Technology

China: ~3 Mcts

- Ningbo CrysDiam Industrial
- Shanghai Zheng Shi Technology
- Zhengzhou Sino-Crystal Diamond
- Zhongan Diamond
- Henan Huanghe Whirlwind

Singapore: ~1 Mcts

- IIa Technologies
- Trosik

